

Substitute for form 1449A/PTO

Sheet

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Co	mplete it	Known
Application Number	10/585,582	
Filing Date	July 10	0, 2006
First Named Inventor	Alexar	nder FINKELSTEIN
Group Art Unit	2891	Confirmation No. 6641
Examiner Name	Matthe	ew L. REAMES
Attorney Docket Number	FINKELSTEIN=1	

			U.S. PA	TENT DOCUMENTS	
Examiner	Cite No.1	Document Number Number-Kind Code ^{2 (if known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US- 6,355,953 B1	03-12-2002	George KIRCZENOW	
	AB	US-2003/0075772 A1	04-24-2003	Alexander EFROS et al.	
	_	US-			
		US-			
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		NON PATENT LITERATURE DOCUMENTS /OTHER INFORMATION				
Examiner Cite Initials* No.1		Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published				
	AC	S. A. WOLF et al., "Spintronics: A Spin-Based Electronics Vision for the Future", SCIENCE, Vol. 294, pp. 1488 - 1495, November 16, 2001				
	AD	H. OHNO et al., "Semiconductor Spin Electronics", JSAP International, Mo. 5, pp. 4-13, January 2002.				
	AE	Gary PRINZ, "Magnetoelectronics", SCIENCE, Vol. 282, pp. 1660-1663, November 27, 1998.				
	AF Mark JOHNSON et al., "Interfacial Charge-Spin Coupling: Injection and Detection of Spin Magnetization in Metals", Vol. 55, No. 17, pp. 1790-1793, October 21, 1985.					
	AG	R. FIEDERLING et al., "Injection and Detection of a spin-polarized current in a light-emitting diode", NATURE, Vol. 402, pp. 787-789, December 16, 1999.				
	АН	Y. OHNO et al., "Electrical spin injection in a ferromagnetic semiconductor heterostructure". NATURE, Vol. 402, pp. 790-792, December 16, 1999.				
AI		Vladimir Ya. KRAVCHENO et al., "Spin inection into a ballistic semiconductor microstructure", Physical Review B, Vol. 67, pp. 121310-1 - 121310-4, 2003.				
	AJ	G. F. DRESSELHAUS, "Spin-Orbit Coupling Effects in Zinc Blende Structures", Physical Review, Vol. 100, No. 2, pp. 580-586, October 15, 1955.				
	AK	E. I. RASHBA, "Properties of Semiconductors with an Extremum Loop I. Cyclotron and Combinatorial Resonance in a Magnetic Field Perpendicular to the Plane of the Loop", Soviet Physics - Solid State, Vol. 2, pp. 1109-1122, June 1960.				
Exami Signat		Date Considered				

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. \(^1\) Applicant's unique citation designation number (optional). \(^2\) See Kind Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. \(^3\) Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). \(^4\)For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. \(^5\) Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. \(^6\) Applicant is to place a check mark here if English language Translation is attached.

Complete if Known Substitute for form 1449A/PTO 10/585,582 Application Number INFORMATION DISCLOSURE July 10, 2006 Filing Date Alexander FINKELSTEIN STATEMENT BY APPLICANT First Named Inventor Confirmation No. 6641 2891 Group Art Unit Matthew L. REAMES (use as many sheets as necessary) **Examiner Name** FINKELSTEIN=1 of Attorney Docket Number Sheet 2

NON PATENT LITERATURE DOCUMENTS /OTHER INFORMATION				
Cite No.1	Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²		
AL	Yu A. BYCHKOV et al., "Oscillatory effects and the magnetic susceptibility of carriers in inversion layers", <u>J. Phys. C. Solid State Phys.,</u> Vol. 17, pp. 6039-6045, 1984.			
AM	J. LUO et al., "Effects of inversion asymmetry on electron energy band structures in GaSb/InAs/GaSb quantum wells", Phys. Review B, Vol. 41, No. 11, pp. 7685-7693, April 15, 1990.	-		
AN	Simon M. SZE, "Semiconductor Devices: Physics and Technology", Wiley Text Books, 2 nd Edition, pp. 246-253 and 332-368, September 2001.			
AO	Y. SATO et al., "Large spontaneous spin splitting in gate-controlled two-dimensional electron gases at normal In _{0.75} Ga _{0.25} As/In _{0.75} Al _{0.25} As heterojunctions". <u>Journal of Applied Physics</u> , Vol 89, No. 12 pp. 8017-8021, June 15, 2001.			
AQ	lgor ZUTIC et al., "Spintronics: Fundamentals and applications", Review of Modern Physics, Vol. 76, pp. 323-410, April 2004.			
AR	A. A. KISELEV et al., "T-shaped spin filter with a ring resonator", Journal of Applied Physics, Vol. 94, No. 6, pp. 4001-4005, September 15, 2003.			
AS	A. A. KISELEV et al., "T-shaped ballistic spin filter", Applied Physics Letters, Vol. 78, No. 6, pp. 775-777, February 5, 2001.			
АТ	Sanker Das. SARMA, "Spintronics", American Scientist, Vol. 89, pp. 516, November 2001.			
AU	I. I. RABI, "Space Quantization in a Gyrating Magnetic Field", Physical Review, Vol. 51, pp. 652-654, April 15, 1937.			
AV	J. SPECTOR et al., "Control of ballistic electrons in macroscopic two-dimensional electron systems", Appl. Phys. Letters, Vol. 56, No. 10, pp. 967-969, March 5, 1990.			
	AM AN AO AP AQ AR AS	Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the Item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published AL Yu A. BYCHKOV et al., "Oscillatory effects and the magnetic susceptibility of carriers in inversion layers", J. Phys. C. Solid State Phys., Vol. 17, pp. 6039-6045, 1984. AM J. LUO et al., "Effects of inversion asymmetry on electron energy band structures in GaSb/InAs/GaSb quantum wells", Phys. Review B, Vol. 41, No. 11, pp. 7685-7693, April 15, 1990. AN Simon M. SZE, "Semiconductor Devices: Physics and Technology", Wiley Text Books, 2 nd Edition, pp. 246-253 and 332-368, September 2001. AO Y. SATO et al., "Large spontaneous spin splitting in gate-controlled two-dimensional electron gases at normal InangGaa2sAs/InangAla2sAs heterojunctions". Journal of Applied Physics, Vol 89, No. 12 pp. 8017-8021, June 15, 2001. AP P. M. MORSE et al., "Methods of Theoretical Physics I", Chapter 12.2 Distribution Functions for Diffusion Problems, pp. 1606-1638, June 1953. AQ Igor ZUTIC et al., "Spintronics: Fundamentals and applications", Review of Modern Physics, Vol. 76, pp. 323-410, April 2004. AR A. A. KISELEV et al., "T-shaped spin filter with a ring resonator", Journal of Applied Physics, Vol. 94, No. 6, pp. 4001-4005, September 15, 2003. AS A. A. KISELEV et al., "T-shaped spin filter with a ring resonator", Journal of Applied Physics, Vol. 78, No. 6, pp. 775-777, February 5, 2001. AT Sanker Das. SARMA, "Spintronics", American Scientist, Vol. 89, pp. 516, November 2001. AU I. RABI, "Space Quantization in a Gyrating Magnetic Field", Physical Review, Vol. 51, pp. 652-654, April 15, 1937. AV J. SPECTOR et al., "Control of ballistic electrons in macroscopic two-dimensional electron systems", Appl. Phys.		

Examiner	Date
Signature	 Considered

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¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

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INFORMATION DISCLOSURE			Application Number	10/58	10/585,582	
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STATEMENT BY APPLICANT (use as many sheets as necessary)		First Named Inventor				
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		Examiner Name	Matthew L. REAMES			
Sheet 3 3		Attorney Docket Number	FINKELSTEIN=1			
		<u> </u>				

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	AW	L. W. MOLENKAMP et al., "Electron-beam collimation with a quantum point contact", Physical Review B, Vol. 41, No. 2, pp. 1274-1277, January 15, 1990.				
	AX Yu A. BYCHKOV et al., "Properties of a 2D electron gas with lifted spectral degeneracy", <u>JETP Letters</u> , Vol. 39 No. 2, pp. 78-81, January 25, 1984.					
	AY	S. DATTA et al., "Electronic analog of the electro-optic modulator", Applied Physics Letters, Vol. 56, No. 7, pp. 665-667, February 12, 1990.				
	AZ	Z J. LUO et al., "Observation of the zero-field spin splitting of the ground electron subband in GaSb-In-As-GaSb quantum wells", Physical Review B, Vol. 38, No. 14, pp. 10142-10145, November 15, 1988.				
	ВА	A B. DAS et al., "Evidence for spin-splitting in In _x Ga _{1-x} As/In _{0.52} AI _{0.48} As heterostructures as B→0", Physical Review B, Vol. 39, No. 2, pp. 1411-1414, January 15, 1989.				
	BB J. NITTA et al., "Gate Control of Spin-Orbit Interaction in an Inverted In _{0.53} Ga _{0.47} As/In _{0.52} Al _{0.48} As Heterostructure Physical Review Letters, Vol. 78, No. 7, pp. 1335-1338, February 17, 1997. BC G. ENGELS et al., "Experimental and theoretical approach to spin splitting in modulation-doped InxGa _{1-x} As/InFquantum wells for B→0", Physical Review B, Vol. 55, No. 4, pp. R1958-R1961, January 15, 1997.					
	BD	S. J. PAPADAKIS et al., "Spin-splitting in GaAs two-dimensional holes", Physica E, Vol. 9, pp. 31-39, 2001.				
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